

APPROVAL SHEET

MULTILAYER CERAMIC CAPACITORS

Safety Certified X2 Series

1808 to 1812 Sizes

NP0 & X7R Dielectrics

RoHS Compliance

*Contents in this sheet are subject to change without prior notice.



1. INTRODUCTION

WTC's SAFETY CERTIFIED CAPACITORS are designed for surge or lightning immunity in modem facsimile and other equipments. The capacitors of series S3 are class X2 compliant respectively.

The green type capacitors in S2 and S3 series are manufactured by using environmentally friendly materials without lead or cadmium.

The terminations are composed of plated nickel and pure tin to feature the superior leaching resistance during soldering.

2. FEATURES

- a. High reliability and stability.
- b. Small size and high capacitance
- c. RoHS compliant
- d. Safety standard approval by EN 60384-14, UL 60384-14, UL 60950
- e. Certificate number:

TUV: R50195920,UL: E250427, E182369

f. HALOGEN compliant

3. APPLICATIONS

- a. Modem.
- b. Facsimile.
- c. Telephone.
- d. Other electronic equipment for lighting or surge protection and isolation.





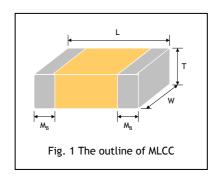
4.HOW TO ORDER

<u>S3</u>	<u>42</u>	<u>N</u>	<u>100</u>	<u>J</u>	302	<u>L</u>	I
<u>Series</u>	<u>Size</u>	Dielectric	<u>Capacitance</u>	Tolerance	Rated voltage	<u>Termination</u>	<u>Packaging</u>
S3 =X2	42 =1808 (4520)	N=NP0	Two significant	B = ±0.1pF	Two significant digits	C =Cu/Ni/Sn	T=7" reeled
Safety	43 =1812 (4532)	B =X7R	digits followed by	C = ±0.25pF	followed by no. of	L=Ag/Ni/Sn	
Certified			no. of zeros. And R	D = ±0.5pF	zeros. And R is in		
			is in place of	F= ±1.0%	place of decimal		
			decimal point.	G = ±2.0%	point.		
				J = ±5.0%	000 00001/D0		
			eg.:	K = ±10%	202 : 2000VDC 302 : 3000VDC		
			0R5=0.5pF	M = ±20%	002. 0000 120		
			1R0=1.0pF				
			100=10x10 ⁰				
			=10pF				



5. EXTERNAL DIMENSIONS & STRUCTURE

Size Inch (mm)	L (mm)	W (mm)	T (mm)	M _B (mm)
1206 (3216)	3.20±0.20	1.60±0.20	1.25±0.10	≥ 0.25
1808 (4520)	4.50±0.50	2.03±0.25	1.25±0.10 (D) 1.40±0.15 (F)	≥ 0.26
1812 (4532)	4.50±0.50	3.20±0.40	1.60±0.20 (G) 2.00±0.20 (K) 2.50±0.30 (M)	≥ 0.26
2220 (5750)	5.70±0.40	5.00±0.40	2.50±0.30 (M)	≥ 0.30



6.GENERAL ELECTRICAL DATA

Dielectric	NP0 X7R			
Size	1808, 1812			
Capacitance*	3.9pF to 1000pF	150pF to 2700pF		
Capacitance tolerance	J (±5%), K (±10%)	K (±10%), M (±20%)		
Rated voltage (WVDC)	2000V,	3000V		
Rated voltage (WVAC)	250Vrms			
Q/ DF(Tan δ)	Cap<30pF: Q≥400+20C Tan δ≤2.5%			
Insulation resistance at Ur	≥10GΩ			
Dielectric withstanding strength	1500VAC			
Peak impulse voltage (X2)	2500V			
Operating temperature	-55 to -	+125°C		
Capacitance characteristic	±30ppm ±15%			
Termination	Ni/Sn (lead-free termination)			
Certified number	R50195920, UL: E250427, E182369			
Test standard	60384-14:2013, UL 609	950:2000, UL 60384-14		

^{*} NPO: Apply 1.0±0.2Vrms, 1.0MHz±10%, at 25°C ambient temperature X7R: Apply 1.0±0.2Vrms, 1.0kHz±10%, at 25°C ambient temperature.

7.PACKAGE DIMENSION AND QUANTITY

Size	Thickness (mm)/Symbol		Plastic tape	
Size	Thickness (IIIII)/Sy	IIIDOI	7" reel	13" reel
	1.40±0.15	F	2k	-
1808 (4520)	1.60±0.20	G	2k	8k
	2.00±0.20	K	1k	6k
	1.25±0.10	D	1k	
4040 (4500)	1.60±0.20	G	1k	
1812 (4532)	2.00±0.20	K	1k	-
	2.50±0.30	M	0.5k	3k

Unit: pieces



8-1.CAPACITANCE RANGE-NME TYPE

	DIELECTRIC	N	P0
	SIZE	18	808
RA	TED VOLTAGE (VDC)	2000	3000
	3.9pF (3R9)	F *	F*
	4.7pF (4R7)	F*	F*
	5.0pF (5R0)	F*	F*
	5.6pF (5R6)	F*	F*
	6.8pF (6R8)	F*	F*
	8.2pF (8R2)	F*	F*
	10pF (100)	F*	F*
	12pF (120)	F*	F*
	15pF (150)	F*	F*
	18pF (180)	F*	F*
	22pF (220)	F*	F*
	27pF (270)	F*	F*
	33pF (330)	F*	F*
ø	39pF (390)	G*	G*
auc	47pF (470)	G*	G*
ic it	56pF (560)	G*	G*
Capacitance	68pF (680)	G*	G*
S	82pF (820)	G*	G*
	100pF (101)	K*	K*
	120pF (121)	K*	K*
	150pF (151)	K*	K*
	180pF (181)	K*	K*
	220pF (221)	K*	K*
	270pF (271)	K*	K*
	330pF (331)	K*	K*
	390pF (391)	K*	K*
	470pF (471)	K*	K*
	560pF (561)	K*	K*
	680pF (681)	K*	K*
	820pF (821)	K*	K*
	1,000pF (102)	K*	K*

- 1. The letter in cell is expressed the symbol of product thickness.
- 2. For more information about products with special capacitance or other data, please contact WTC local representative.
- 3. The letter in cell with "*" mark is expressed product with Ag/Ni/Sn terminations.

	DIELECTRIC			X7R	
	SIZE	1808		1	812
RA	TED VOLTAGE (VDC)	2000	3000	2000	3000
	150pF (151)				
	180pF (181)	G*	G*		
	220pF (221)	G*	G*		
	270pF (271)	G*	G*		
	330pF (331)	G*	G*	G*	G*
	390pF (391)	G*	G*	G*	G*
	470pF (471)	G*	G*	G*	G*
o)	560pF (561)	G*	G*	G*	G*
ũ	680pF (681)	G*	G*	G*	G*
Capacitance	820pF (821)	G*	G*	G*	G*
ac	1,000pF (102)	K*	K*	G*	G*
ўаb	1,200pF (122)	K*	K*	G*	G*
J	1,500pF (152)	K*	K*	K*	K*
	1,800pF (182)	K*	K*	K*	K*
	2,200pF (222)			M*	M*
	2,700pF (272)			M*	M*
	3,300pF (332)				
	3,900pF (392)				
	4,700pF (472)				
	5,600pF (562)				

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8-2.CAPACITANCE RANGE-BME TYPE

RATED	SIZE VOLTAGE (VDC) 3.9pF (3R9) 4.7pF (4R7) 5.0pF (5R0) 5.6pF (5R6)	1 2000 F F F	808 3000 F F
RATED	3.9pF (3R9) 4.7pF (4R7) 5.0pF (5R0)	F F	F
	4.7pF (4R7) 5.0pF (5R0)	F	-
	5.0pF (5R0)	<u> </u>	F
		F	
			F
		F	F
	6.8pF (6R8)	F	F
	8.2pF (8R2)	F	F
	10pF (100)	F	F
	12pF (120)	F	F
	15pF (150)	F	F
	18pF (180)	F	F
	22pF (220)	F	F
	27pF (270)	F	F
	33pF (330)	F	F
<u>8</u>	39pF (390)	G	G
Capacitance	47pF (470)	G	G
gcit	56pF (560)	G	G
<u>a</u>	68pF (680)	G	G
ပ	82pF (820)	G	G
	100pF (101)	К	K
	120pF (121)	K	K
	150pF (151)	K	K
	180pF (181)	K	K
	220pF (221)	К	K
	270pF (271)	К	K
	330pF (331)	К	K
	390pF (391)	К	K
	470pF (471)	K	K
	560pF (561)	К	K
	680pF (681)	К	K
	820pF (821)	K	K
	1,000pF (102)	К	K

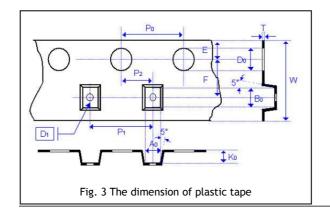
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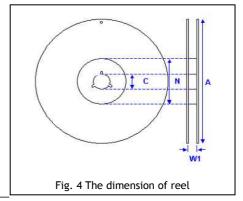
	DIELECTRIC		Х	7R	
	SIZE	1808		1812	
RA'	TED VOLTAGE (VDC)	2000	3000	2000	3000
	150pF (151)				
	180pF (181)	G	G		
	220pF (221)	G	G		
	270pF (271)	G	G		
	330pF (331)	G	G	G	G
	390pF (391)	G	G	G	G
	470pF (471)	G	G	G	G
ω.	560pF (561)	G	G	G	G
Capacitance	680pF (681)	G	G	G	G
<u> </u>	820pF (821)	G	G	G	G
ac	1,000pF (102)	K	K	G	G
ap	1,200pF (122)	K	K	G	G
0	1,500pF (152)	K	K	K	K
	1,800pF (182)	K	K	K	K
	2,200pF (222)			M	M
	2,700pF (272)			M	M
	3,300pF (332)				
	3,900pF (392)				
	4,700pF (472)				
	5,600pF (562)				

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EMBOSSED TAPE DIMENSIONS





Size	1206	18	08	18	12	22	20
Chip Thickness	1.25±0.10	1.25±0.10 1.40±0.15 1.60±0.20	2.00±0.20	1.25±0.10 1.60±0.20 2.00±0.20	2.50±0.30	2.00±0.20	2.50±0.30
A_0	< 2.00	<2.50	<2.50	<3.90	<3.90	<3.30	<3.30
B_0	< 3.60	<5.30	<5.30	<5.30	<5.30	<6.50	<6.50
Т	0.23±0.05	0.25±0.05	0.25±0.05	0.25±0.05	0.25±0.05	0.30±0.10	0.30±0.10
K ₀	< 2.50	<2.50	<2.50	<2.50	<3.00	<2.50	<3.10
W	8.0±0.20	12.0±0.20	12.0±0.20	12.0±0.20	12.0±0.20	12.0±0.20	12.0±0.20
P_0	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10
10xP₀	40.0±0.20	40.0±0.20	40.0±0.20	40.0±0.20	40.0±0.20	40.0±0.20	40.0±0.20
P ₁	4.00±0.10	4.00±0.10	4.00±0.10	8.00±0.10	8.00±0.10	8.00±0.10	8.00±0.10
P ₂	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05
D_0	1.50+0.10/-0	1.50+0.10/-0	1.50+0.10/-0	1.50±0.10/-0	1.50+0.10/-0	1.50+0.10/-0	1.50+0.10/-0
D ₁	1.00±0.10	1.50±0.10	1.50±0.10	1.50±0.10	1.50+/-0.10	1.50±0.10	1.50±0.10
E	1.75±0.10	1.75±0.10	1.75±0.10	1.75±0.10	1.75+/-0.1	1.75±0.1	1.75±0.10
F	3.50±0.05	5.50±0.05	5.50±0.05	5.50±0.05	5.50+/-0.05	5.50±0.05	5.50±0.05

Size	1206	1808, 1812, 2220
Reel size	7"	7"
С	13.0+0.5/-0.2	13.0+0.5/-0.2
W ₁	8.4+1.5/-0	12.4+2.0/-0
Α	178.0±1.0	178.0±1.0
N	60.0+1.0/-0	80.0±1.0



9. APPLICATION NOTES

Storage

To prevent the damage of solderability of terminations, the following storage conditions are recommended: Indoors under $5 \sim 40^{\circ}\text{C}$ and $20\% \sim 70\%$ RH.

No harmful gases containing sulfuric acid, ammonia, hydrogen sulfide or chlorine.

Packaging should not be opened until the capacitors are required for use. If opened, the pack should be re-sealed as soon as is practicable. Taped product should be stored out of direct sunlight, which might promote deterioration in tape or adhesion performance. The capacitors should be used within 6 months and checked the solderability before use.

Handling

Chip capacitors are dense, hard, brittle, and abrasive materials. They are liable to suffer mechanical damage, in the form of cracks or chips. Chip Capacitors should be handled with care to avoid contamination or damage. To use vacuum or plastic tweezers to pick up or plastic tweezers is recommended for manual placement. Tape and reeled packages are suitable for automatic pick and placement machine.

Preheat

In order to minimize the risk of thermal shock during soldering, a carefully controlled preheat is required. The rate of preheat should not exceed 4°C per second and the final preheat temperature should be within 100°C of the soldering temperature for small chips such as 0402, 0603, 0805 and 1206, within 50°C of the soldering temperature for bigger chips such as 1210, 1808, 1812, 1825, 2220 and 2225, etc.

Soldering

Use middy activated rosin RA and RMA fluxes do not use activated flux. The amount of solder in each solder joint should be controlled to prevent the damage of chip capacitors caused by the stress between solder, chips, and substrate.

Hand soldering with temperature-controlled iron not exceeding 30 watts and diameter of tip less than 1.2 mm is recommended, tip of iron should not contact the ceramic body directly, and the temperature of iron should be set to not more than 260°C.

For bigger chips such as 1210, 1808, 1812, 2220 and 2225, etc. wave soldering and hand soldering are no recommended.

Refer IPC/JEDEC J-STD-020D Method recommended soldering profiles:

Reflow not sooner than 15 minutes and not longer than 4 hrs after removal from the temperature/humidity chamber, subject the sample to 3 cycle of the appropriate reflow conditions as defined as blow Table description.

Profile Feature	Pb-Free Assembly
Preheat/Soak	·
Temperature Min.(T _{S min})	150°C
Temperature Max.(T _{S max})	200°C
Time(t_S) from ($T_{S min}$ to $T_{S max}$)	60 to 120 seconds
Ramp-up rate(T _L to T _P)	3°C/second max.
Liquidous temperature(T _L)	217°C
Time(t _L) maintained above T _L	60 to 150 seconds
	For user T _P must not exceed the Classification temp 260°C
Peak package body temperature(T _P)	For suppliers T _P must equal or exceed the Classification temp 260°C
$Time(T_P)^*$ within 5°C of the specified classification temperature(T_C)	30* second
Ramp-down rate (T _P to T _L)	6°C/second max.
Time 25°C to peak temperature 260°C	8 minutes max.

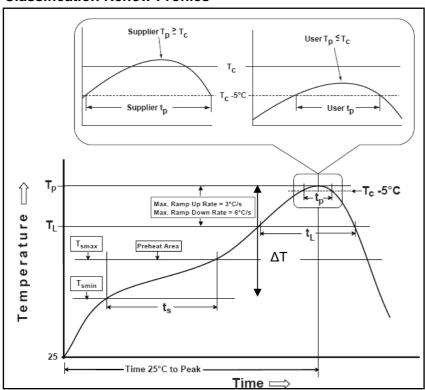


Lead-free: Soldering temperature = 235 to 260°C, depending on product.

Maximum temperature = Minimum temperature (235°C)+ ΔT + Tolerance for oven process and measurement(5 ~ 7°C)

Time at peak temperature = 10sec, Dwell above 217°C = 90sec, Ramping rate = 3°C/sec (heating) and 6°C/sec (heating).

Classification Reflow Profiles



Chip Size	ΔΤ
0805,1206	100 °C
1210, 1808, 1812, 1825, 2211, 2220, 2225	50°C

Soldering	Solder Temp.(T _C)	Soldering Time (t _P)	
Reflow	235 – 260 °C	< 15 sec.	

Note: For example, T_C is 260°C and time t_P is 15 seconds.

For user: The peak temperature must not exceed 260°C. The time above 255°C must not exceed 15 seconds.

Cooling

After soldering, cool the chips and the substrate gradually to room temperature. Natural cooling in air is recommended to minimize stress in the solder joint. A cooling rate not exceeding 4°C per second should be used when forced cooling is necessary.

Cleaning

All flux residues must be removed by using suitable electronic-grade vapor-cleaning solvents to eliminate contamination that could cause electrolytic surface corrosion. Good results can be obtained by using ultrasonic cleaning of the solvent. The choice of the proper system is depends upon many factors such as component mix, flux, and solder paste and assembly method. The ability of the cleaning system to remove flux residues and contamination from under the chips is very important.



10.RELIABILITY TEST CONDITIONS AND REQUIREMENTS

No.	Item	Standard Methods	Test Condition	Requirements				
1.	Visual examination and Dimensions	IEC 60384-1 4.1		* No remarkable defect. * Dimensions to confirm to individual specification sheet.				
	Capacitance D.F.	IEC 60384-1 4.2.2 IEC 60384-1	Class I: C0G(NP0) Cap≤1000pF, 1.0±0.2Vrms, 1MHz±10% Cap>1000pF, 1.0±0.2Vrms, 1KHz±10% Class II: (X7R)	* Capacitance is within specified tolerance * C _R means rated capacitance for conform to the E6 series of preferred values given in IEC 60063.				
з.	(Dissipation Factor)	4.2.3	1.0±0.2Vrms, 1kHz±10%				σαρ τουρι	
	Temperature Coefficient	IEC 60384-21/22 4.6	With no electrical load. T.C. Operating Temp C0G(NPO) -55~125°C at 25°C X7R -55~125°C at 25°C	C0G(N X7F	T.C. Capacitance Change C0G(NPO) Within ±30ppm/°C X7R Within ±15%			
	Insulation Resistance	IEC 60384-21/22 4.5.3	, and the second	Class I (NP0) : $\geq 100 \text{G}\Omega$ or RxC $\geq 1000 \Omega$ -F whichever is smaller. Class II (X7R) : $\geq 10 \text{G}\Omega$ or RxC $\geq 500 \Omega$ -F whichever is smaller.				
6.	Voltage proof (Dielectric Strength)	IEC 60384-14 4.2.1	 * To apply voltage: X Capacitor: 1075Vdc (4.3U_R) Y Capacitor: 1500Vac * Duration: 60 sec. * The charge current shall not exceed 0.05A. 	* No evidence of damage or flashover during test. * The voltage shall be raised from the near zero to the test volt rate not exceeding 150V(r.m.s.)/sec.				
7.	Solderability	IEC 60384-21/22 4.10	* Solder temperature: 245±5°C * Dipping time: 2±0.2 sec.	75% min. coverage of all metalized area.				
8.	Resistance to Soldering Heat	IEC 60384-14 4.4 IEC 60384-21/22 4.9	* Solder temperature: 260±5°C * Dipping time: 10±1 sec * Preheating: 120 to 150°C for 1 minute before immerse the capacitor in a eutectic solder. * Before initial measurement (Class II only): Perform 150+0/-10°C for 1 hr and then set for 24±2 hrs at room temp. * Measurement to be made after keeping at room temp. for 24±2 hrs (Class II) and 24±2 hrs (Class II)	* No visibl Dielectric Class I (NPO) Class II (X7R)			Cap Change Within ±2.5% or ±0.25pF whichever is larger. within ±7.5%	Q/D.F ≤ 1.0 × Initial requirement
9.	Humidity (Damp Heat) Steady State	IEC 60384-14 4.12	* Test temp.: 40±2°C * Humidity: 90~95% RH * Test time: 500+24/-0hrs. * Applied Voltage:250Vac * Measurement to be made after keeping at room temp. for 24±2 hrs (Class I) and 24±2 hrs (Class II)	* No rema Dielectric Class I (NPO) Class II	I.R	or RxC≥	Cap Change within ±3.0% or ±2pF whichever is larger	Q/D.F ≤ 0.25 % D.F. ≤ 2 × Initial
10.	Passive Flammability	IEC 60384-14 4.17 IEC 60384-1 4.38	* Volume sample: 21.56 mm ³ * Flame exposure time: 5 sec Max. * Category of flammability : C.	within ±15% requirement * Capacitor didn't burn at all				
11.	Active Flammability	IEC 60384-14 4.17 IEC 60384-1 4.38	* The capacitors applied UR (250Vac). Then each sample shall be subjected to 20 discharges from a tank capacitor, charge to a voltage that, when discharged, plase Ui 2500V for X2, Ui 5000V for X1Y2 across the capacitor under test. The interval between successive discharges shall be 5 sec.	* The cheese cloth shall not burn with a flame.				

No.	Item	Standard Methods	Test Condition	Requirements	
12.	Endurance	IEC 60384-14 4.14	* Impulse Voltage: Each individual capacitor shall be subjected to a Vp = 5.0KV (X1Y2 Class Impulse 5KV) & Vp = 6.0KV (X1Y2 Class Impulse 6KV) impulse for three times before applied to endurance test. *Test Temp.: 125±3°C * Test time:: 1000+48/-0 hrs. * Applied Voltage: X capacitor: 1.25U _R (312.5Vac) Y capacitor: 1.70U _R (425Vac) Once every hour the voltage shall be increased to 1000Vrms for 0.1 sec. * Measurement to be made after keeping at room temp. for 24±2 hrs (Class I) and 24±2 hrs (Class II)	* Appearance : No mechanical damage. * Cap change: NP0 within ±5% or ±0.5pF whichever is larger X7R within ±20% * D.F Value: NP0 ≤ 0.25% X7R: ≤5.0% * I.R. ≥1GΩ * Dielectric strength satisfies the specified initial value	
13.	Resistance to Flexure of Substrate	IEC 60384-21/22 4.8	* Capacitors mounted on a substrate. The board shall be bent 1mm with a rate of 1mm/sec. $\begin{array}{c} 20 \\ \hline \\ 50 \\ \hline \end{array}$	* No remarkable damage. Dielectric Cap Change Class I (NPO) within ±3.0% or ±2pF whichever is larger Class II (X7R) within ±12.5% (This capacitance change means the change of capacitance under specified flexure of substrate from the capacitance measured before the test.)	
14.	Robustness of terminations (Adhesive Strength of Termination)	IEC 60384-21/22 4.15 IEC 60384-1 4.13	* Capacitors mounted on a substrate. A force of 10N applied perpendicular to the place of substrate and parallel the line joining the center of terminations for 10±1 sec. Pressurizing force PC Board Capacitor	* No remarkable damage or removal of the terminations.	
15.	Impulse Voltage	IEC 60384-14 4.13	* X1 : 4.0KV, X2 : 2.5KV. * Y2 : 5.0KV, * Number of impulse : 24 max.	*There shall be no permanent breakdown or flashover.	